

Thierry Kohl

List of Publications by Year in descending order

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papers

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| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | Innovative and industrially viable approach to fabricate AlO _x rear passivated ultra-thin Cu(In, Ga)Se ₂ (CIGS) solar cells. Solar Energy, 2020, 207, 1002-1008. | 6.1 | 23 |
| 2 | High V_{oc} upon KF Post-Deposition Treatment for Ultrathin Single-Stage Coevaporated Cu(In, Ga)Se ₂ Solar Cells. ACS Applied Energy Materials, 2019, 2, 6102-6111. | 5.1 | 22 |
| 3 | A study to improve light confinement and rear-surface passivation in a thin-Cu(In, Ga)Se ₂ solar cell. Thin Solid Films, 2019, 669, 399-403. | 1.8 | 18 |
| 4 | Rear surface passivation of ultra-thin CIGS solar cells using atomic layer deposited HfO _x . EPJ Photovoltaics, 2020, 11, 10. | 1.6 | 17 |
| 5 | Inclusion of Water in Cu(In, Ga)Se ₂ Absorber Material During Accelerated Lifetime Testing. ACS Applied Energy Materials, 2020, 3, 5120-5125. | 5.1 | 14 |
| 6 | Fabrication of high band gap kesterite solar cell absorber materials for tandem applications. Thin Solid Films, 2018, 660, 247-252. | 1.8 | 13 |
| 7 | Alkali treatment for single-stage co-evaporated thin CuIn _{0.7} Ga _{0.3} Se ₂ solar cells. Thin Solid Films, 2019, 671, 44-48. | 1.8 | 13 |
| 8 | Bias-Dependent Admittance Spectroscopy of Thin-Film Solar Cells: Experiment and Simulation. IEEE Journal of Photovoltaics, 2020, 10, 1102-1111. | 2.5 | 13 |
| 9 | Crystallization properties of Cu ₂ ZnGeSe ₄ . Thin Solid Films, 2019, 670, 76-79. | 1.8 | 10 |
| 10 | Intermediate scale bandgap fluctuations in ultrathin Cu(In,Ga)Se ₂ absorber layers. Journal of Applied Physics, 2020, 128, 163102. | 2.5 | 5 |
| 11 | Study of Ammonium Sulfide Surface Treatment for Ultrathin Cu(In,Ga)Se ₂ with Different Cu/(Ga+In) Ratios. Physica Status Solidi (A) Applications and Materials Science, 2020, 217, 2000307. | 1.8 | 5 |
| 12 | Comparative Study of Al ₂ O ₃ and HfO ₂ for Surface Passivation of Cu(In,Ga)Se ₂ Thin Films: An Innovative Al ₂ O ₃ /HfO ₂ Multistack Design. Physica Status Solidi (A) Applications and Materials Science, 2021, 218, 2100073. | 1.8 | 5 |
| 13 | Novel cost-effective approach to produce nano-sized contact openings in an aluminum oxide passivation layer up to 30 nm thick for CIGS solar cells. Journal Physics D: Applied Physics, 2021, 54, 234004. | 2.8 | 4 |
| 14 | Detrimental Impact of Na Upon Rb Postdeposition Treatments of Cu(In,Ga)Se ₂ Absorber Layers. Solar Rrl, 2021, 5, 2100390. | 5.8 | 4 |
| 15 | A Novel Strategy for the Application of an Oxide Layer to the Front Interface of Cu(In,Ga)Se ₂ Thin Film Solar Cells: Al ₂ O ₃ /HfO ₂ Multi-Stack Design With Contact Openings. IEEE Journal of Photovoltaics, 2022, 12, 301-308. | 2.5 | 4 |
| 16 | Wet Processing in State-of-the-Art Cu(In,Ga)(S,Se) ₂ Thin Film Solar Cells. Solid State Phenomena, 2018, 282, 300-305. | 0.3 | 3 |
| 17 | KF Postdeposition Treatment in N ₂ of Single-Stage Thin Cu(In,Ga)Se ₂ Absorber Layers. IEEE Journal of Photovoltaics, 2020, 10, 255-258. | 2.5 | 3 |
| 18 | Investigating the experimental space for two-step Cu(In,Ga)(S,Se) ₂ absorber layer fabrication: A design of experiment approach. Thin Solid Films, 2021, 738, 138958. | 1.8 | 3 |

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|----|--|-----|-----------|
| 19 | A study of the degradation mechanisms of ultra-thin CIGS solar cells submitted to a damp heat environment. , 2019, , . | | 1 |
| 20 | A multi-stack Al ₂ O ₃ /HfO ₂ design with contact openings for front surface of Cu(In,Ga)Se ₂ solar cells. , 2021, , . | | 1 |
| 21 | Bias dependent admittance spectroscopy of thin film solar cells: KF post deposition treatment, accelerated lifetime testing, and their effect on the CVf loss maps. Solar Energy Materials and Solar Cells, 2021, 231, 111289. | 6.2 | 1 |
| 22 | Comparison of a bottom-up and a top-down approach for the creation of contact openings in a multi-stack oxide layer at the front interface of Cu(In,Ga)Se ₂ . Solar Energy, 2022, 237, 161-172. | 6.1 | 1 |
| 23 | Selenium and Sulphur replacement dynamics in CZTSSe and CZGSSe kesterite materials. , 2018, , . | | 0 |
| 24 | Room temperature photoluminescence analysis of alkali treated single-stage thin Cu(In,Ga)Se ₂ absorber layers. , 2019, , . | | 0 |
| 25 | Study of Room Temperature Photoluminescence For 1-stage Co-Evaporated Ultra-Thin Cu(In,Ga)Se ₂ Solar Cells. , 2019, , . | | 0 |
| 26 | Bias dependent admittance spectroscopy: the impact of sodium supply on the Cu(In,Ga)Se ₂ growth.. , 2021, , . | | 0 |